

Supplementary Information: High-Performance Low-Voltage Transparent Metal-Semiconductor-Metal Ultraviolet Photodetectors Based on Ultrathin Gold Asymmetric Interdigitated Electrodes

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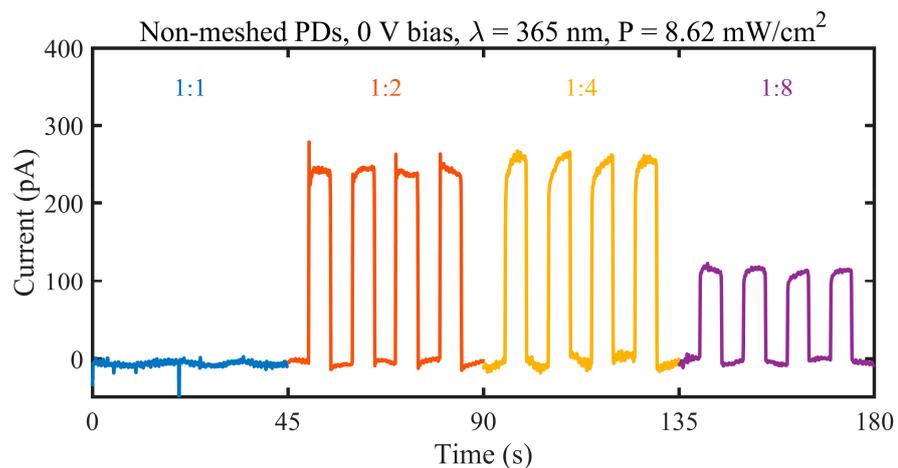


Figure S1. Transient output current of transparent UV PDs with non-meshed pads and aIDT electrodes of different asymmetric ratios under zero bias when the UV light ($\lambda = 365$ nm, $P = 8.62$ mW/cm²) is switched on and off periodically.